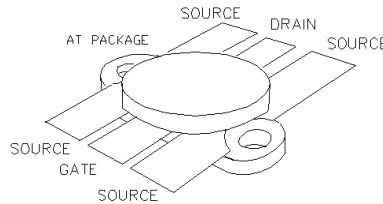




**General Description**

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"™ process features gold metal for greatly extended lifetime. Low output capacitance and high  $F_t$  enhance broadband performance



**PATENTED GOLD METALIZED SILICON GATE ENHANCEMENT MODE RF POWER VDMOS TRANSISTOR**

**60 Watts Single Ended**

**Package Style AT**

**HIGH EFFICIENCY, LINEAR, HIGH GAIN, LOW NOISE**

**ABSOLUTE MAXIMUM RATINGS (TC = 25 °C)**

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
150 Watts	1.2 °C/W	200 °C	-65 °C to 150 °C	8 A	50 V	50V	30V

**RF CHARACTERISTICS ( 60WATTS OUTPUT )**

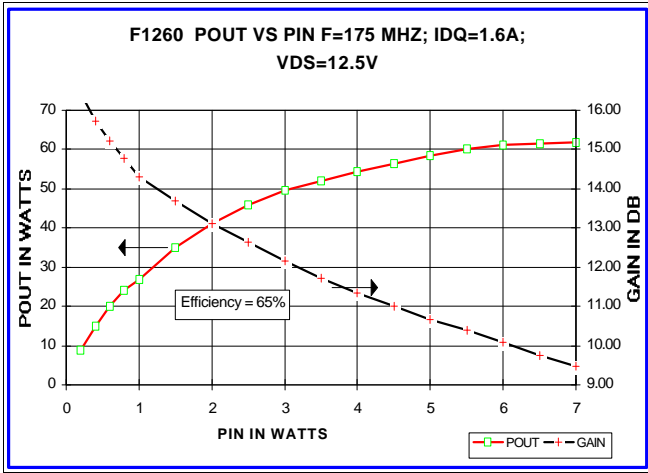
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	10			dB	Idq = 1.6 A, Vds = 12.5V, F = 175 MHz
$\eta$	Drain Efficiency		60		%	Idq = 1.6 A, Vds = 12.5V, F = 175 MHz
VSWR	Load Mismatch Tolerance			20:1	Relative	Idq = 1.6 A, Vds = 12.5V, F = 175 MHz

**ELECTRICAL CHARACTERISTICS (EACH SIDE)**

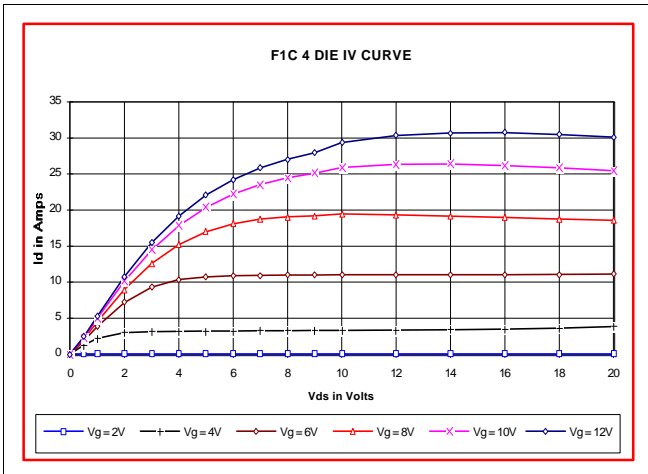
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	40			V	Ids = 0.2 A, Vgs = 0V
Idss	Zero Bias Drain Current			4	mA	Vds = 12.5 V, Vgs = 0V
Igss	Gate Leakage Current			1	uA	Vds = 0 V, Vgs = 30V
Vgs	Gate Bias for Drain Current	1		7	V	Ids = 0.4 A, Vgs = Vds
gM	Forward Transconductance		3.2		Mho	Vds = 10V, Vgs = 5V
Rdson	Saturation Resistance		0.25		Ohm	Vgs = 20V, Ids = 32A
Idsat	Saturation Current		30		Amp	Vgs = 20V, Vds = 10V
Ciss	Common Source Input Capacitance		160		pF	Vds = 12.5 V, Vgs = 0V, F = 1 MHz
Crss	Common Source Feedback Capacitance		24		pF	Vds = 12.5 V, Vgs = 0V, F = 1 MHz
Coss	Common Source Output Capacitance		120		pF	Vds = 12.5 V, Vgs = 0V, F = 1 MHz

# F1260

POUT VS PIN GRAPH

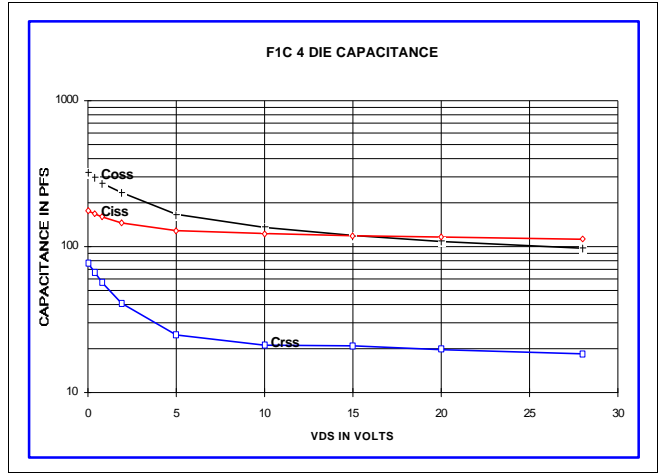


IV CURVE

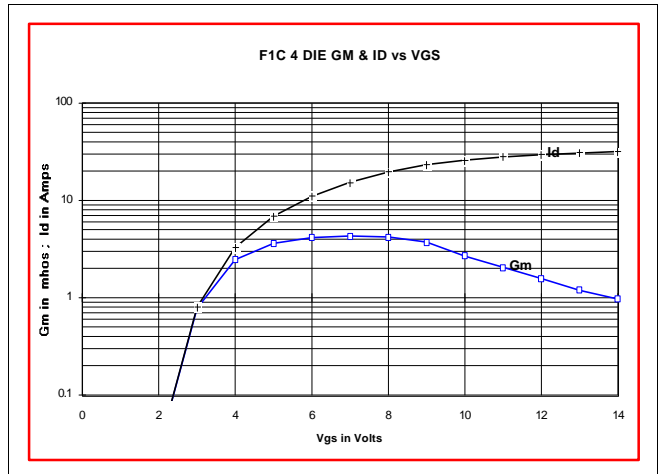


IV CURVE

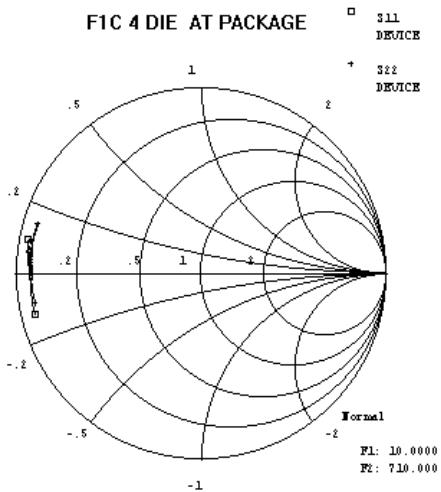
CAPACITANCE VS VOLTAGE



ID AND GM VS VGS



S11 AND S22 SMITH CHART



PACKAGE DIMENSIONS IN INCHES

